74LV4094

8-stage shift-and-store bus register Rev. 4 — 19 December 2011

Product data sheet

General description 1.

The 74LV4094 is a low voltage Si-gate CMOS device and is pin and functional compatible with 74HC4094; 74HCT4094.

The 74LV4094 is an 8-stage serial shift register. It has a storage latch associated with each stage for strobing data from the serial input to parallel buffered 3-state outputs QP0 to QP7. The parallel outputs may be connected directly to common bus lines. Data is shifted on positive-going clock transitions. The data in each shift register stage is transferred to the storage register when the strobe (STR) input is HIGH. Data in the storage register appears at the outputs whenever the output enable (OE) signal is HIGH.

Two serial outputs (QS1 and QS2) are available for cascading a number of 74LV4094 devices. Serial data is available at QS1 on positive-going clock edges to allow high-speed operation in cascaded systems with a fast clock rise time. The same serial data is available at QS2 on the next negative going clock edge. This is used for cascading 74LV4094 devices when the clock has a slow rise time.

Features and benefits 2.

- Optimized for low voltage applications: 1.0 V to 3.6 V
- Accepts TTL input levels between V_{CC} = 2.7 V and V_{CC} = 3.6 V
- Typical output ground bounce < 0.8 V at V_{CC} = 3.3 V and T_{amb} = 25 °C
- Typical HIGH-level output voltage (V_{OH}) undershoot: > 2 V at V_{CC} = 3.3 V and $T_{amb} = 25 \, ^{\circ}C$
- ESD protection:
 - HBM JESD22-A114E exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

Applications

- Serial-to-parallel data conversion
- Remote control holding register



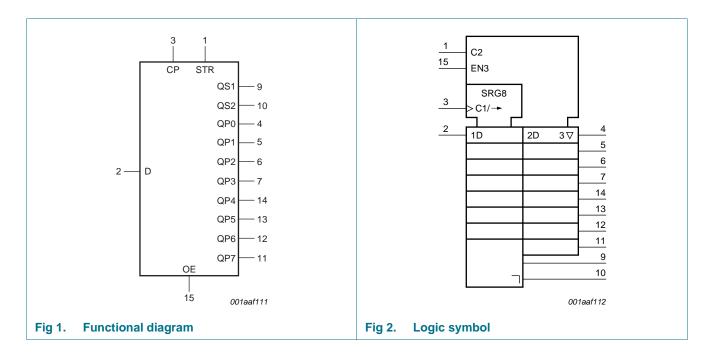
8-stage shift-and-store bus register

4. Ordering information

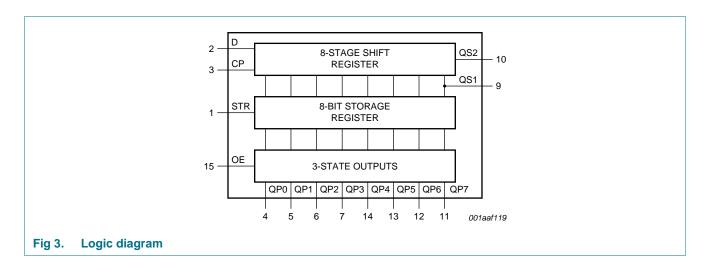
Table 1. Ordering information

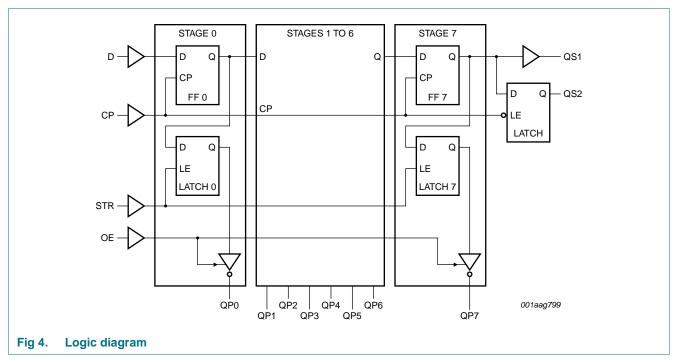
Type number	Package											
	Temperature range	Name	ame Description									
74LV4094N	-40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4								
74LV4094D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1								
74LV4094DB	–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1								
74LV4094PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1								

5. Functional diagram



8-stage shift-and-store bus register

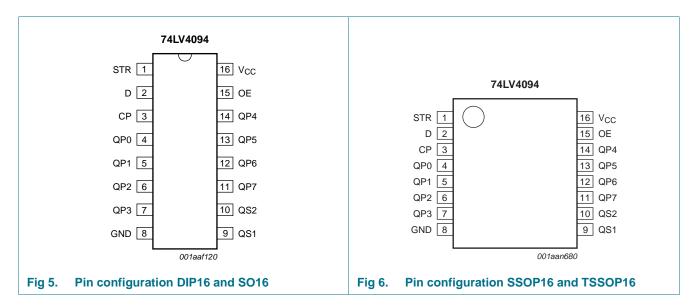




8-stage shift-and-store bus register

6. Pinning information

6.1 Pinning



6.2 Pin description

Table 2. Pin description

Symbol Pin Description STR 1 strobe input D 2 data input CP 3 clock input QP0 to QP7 4, 5, 6, 7, 14, 13, 12, 11 parallel output V _{SS} 8 ground supply voltage QS1, QS2 9,10 serial output OE 15 output enable input V _{DD} 16 supply voltage		The second secon	
D 2 data input CP 3 clock input QP0 to QP7 4, 5, 6, 7, 14, 13, 12, 11 parallel output V _{SS} 8 ground supply voltage QS1, QS2 9,10 serial output OE 15 output enable input	Symbol	Pin	Description
CP 3 clock input QP0 to QP7 4, 5, 6, 7, 14, 13, 12, 11 parallel output V _{SS} 8 ground supply voltage QS1, QS2 9,10 serial output OE 15 output enable input	STR	1	strobe input
QP0 to QP7 4, 5, 6, 7, 14, 13, 12, 11 parallel output V _{SS} 8 ground supply voltage QS1, QS2 9,10 serial output OE 15 output enable input	D	2	data input
VSS8ground supply voltageQS1, QS29,10serial outputOE15output enable input	CP	3	clock input
QS1, QS2 9,10 serial output OE 15 output enable input	QP0 to QP7	4, 5, 6, 7, 14, 13, 12, 11	parallel output
OE 15 output enable input	V _{SS}	8	ground supply voltage
2011/10/2017	QS1, QS2	9,10	serial output
V _{DD} 16 supply voltage	OE	15	output enable input
	V_{DD}	16	supply voltage

8-stage shift-and-store bus register

7. Functional description

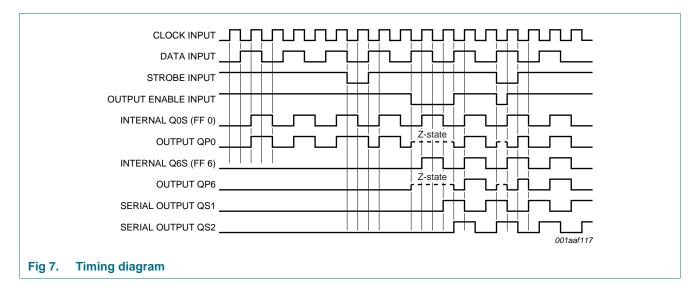
Table 3. Function table[1]

Inputs				Parallel o	utputs	Serial ou	Serial outputs		
СР	OE	STR	D	QP0	QPn	QS1	QS2		
\uparrow	L	X	Χ	Z	Z	Q6S	NC		
\downarrow	L	X	Χ	Z	Z	NC	Q7S		
↑	Н	L	Χ	NC	NC	Q6S	NC		
\uparrow	Н	Н	L	L	QPn –1	Q6S	NC		
\uparrow	Н	Н	Н	Н	QPn –1	Q6S	NC		
\downarrow	Н	Н	Н	NC	NC	NC	Q7S		

^[1] At the positive clock edge, the information in the 7th register stage is transferred to the 8th register stage and the QSn outputs.

Q6S = the data in register stage 6 before the LOW to HIGH clock transition;

Q7S = the data in register stage 7 before the HIGH to LOW clock transition.



H = HIGH voltage level; L = LOW voltage level; X = don't care;

 $[\]uparrow$ = positive-going transition; \downarrow = negative-going transition;

Z = HIGH-impedance OFF-state; NC = no change;

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8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	-	±50	mA
I _O	output current	$V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$	-	±25	mA
I _{CC}	supply current		-	+50	mA
I_{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$			
	DIP16 package		<u>[1]</u> -	750	mW
	SO16 package		[2] -	500	mW
	(T)SSOP16 package		[3] _	500	mW

^[1] For DIP16 package: P_{tot} derates linearly with 12 mW/K above 70 °C.

9. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage		1.0	3.3	3.6	V
VI	input voltage		0	-	V_{CC}	V
Vo	output voltage		0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 1.0 \text{ V to } 2.0 \text{ V}$	-	-	500	ns/V
		$V_{CC} = 2.0 \text{ V to } 2.7 \text{ V}$	-	-	200	ns/V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	-	100	ns/V

^[1] The static characteristics are guaranteed from V_{CC} = 1.2 V to V_{CC} = 5.5 V, but LV devices are guaranteed to function down to V_{CC} = 1.0 V (with input levels GND or V_{CC}).

^[2] For SO16 package: Ptot derates linearly with 8 mW/K above 70 °C.

^[3] For SSOP16 and TSSOP16 packages: Ptot derates linearly with 5.5 mW/K above 60 °C.

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10. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to 85 °C		-40 °C to	+125 °C	Unit	
			Min	Typ[1]	Max	Min	Max	
V_{IH}	HIGH-level	V _{CC} = 1.2 V	V_{CC}	0.6	-	V _{CC}	-	V
	input voltage	V _{CC} = 2.0 V	1.4	-	-	1.4	-	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2.0	-	-	2.0	-	V
V _{IL}	LOW-level	V _{CC} = 1.2 V	-	0.4	GND	-	GND	V
	input voltage	V _{CC} = 2.0 V	-	-	0.6	-	0.6	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; all pins						
	output voltage	$I_O = -100 \mu A; V_{CC} = 1.2 V$	-	1.2	-	-	-	V
		$I_{O} = -100 \mu A; V_{CC} = 2.0 V$	1.8	2.0	-	1.8	-	V
		$I_{O} = -100 \mu A; V_{CC} = 2.7 V$	2.5	2.7	-	2.5	-	V
		$I_O = -100 \mu A; V_{CC} = 3.0 V$	2.8	3.0	-	2.8	-	V
		$V_I = V_{IH}$ or V_{IL} ; pins QPn						
		$I_{O} = -6 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.40	2.82	-	2.20	-	V
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL} ; all pins						
	output voltage	$I_O = 100 \mu A; V_{CC} = 1.2 V$	-	0	-	-	-	V
		$I_O = 100 \mu A; V_{CC} = 2.0 V$	-	0	0.2	-	0.2	V
		$I_O = 100 \mu A; V_{CC} = 2.7 V$	-	0	0.2	-	0.2	V
		$I_O = 100 \mu A; V_{CC} = 3.0 V$	-	0	0.2	-	0.2	V
		$V_I = V_{IH}$ or V_{IL} ; pins QPn						
		$I_{O} = 6 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	0.25	0.40	-	0.50	V
l _l	input leakage current	$V_1 = V_{CC}$ or GND; $V_{CC} = 3.6 \text{ V}$	-	-	±1.0	-	±1.0	μΑ
I _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 3.6 \text{ V}$	-	-	±5.0	-	±10.0	μА
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 3.6$ V	-	-	20.0	-	160	μΑ
ΔI_{CC}	additional supply current	per input; $V_I = V_{CC} - 0.6 \text{ V}$; $V_{CC} = 2.7 \text{ V}$ to 3.6 V	-	-	500.0	-	850	μΑ
Cı	input capacitance		-	3.5	-			pF

^[1] All typical values are measured at T_{amb} = 25 °C.

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11. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); $C_L = 50$ pF unless otherwise specified; for test circuit see Figure 12.

Symbol	Parameter	Conditions		-40	°C to 85	°C	-40 °C 1	to +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
pd	propagation	CP to QS1; see Figure 8	[3]						
	delay	V _{CC} = 1.2 V		-	90	-	-	-	ns
		V _{CC} = 2.0 V		-	31	58	-	70	ns
		V _{CC} = 2.7 V		-	23	43	-	51	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[2]	-	17	34	-	41	ns
		$V_{CC} = 3.3 \text{ V}; C_L = 15 \text{ pF}$		-	14	-	-	-	ns
		CP to QS2; see Figure 8	<u>[3]</u>						
		V _{CC} = 1.2 V		-	80	-	-	-	ns
		V _{CC} = 2.0 V		-	27	51	-	61	ns
		$V_{CC} = 2.7 \text{ V}$		-	20	38	-	45	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		-	14	30	-	36	ns
		$V_{CC} = 3.3 \text{ V}; C_L = 15 \text{ pF}$	[2]	-	13	-	-	-	ns
		CP to QPn; see Figure 8	<u>[3]</u>						
		V _{CC} = 1.2 V		-	115	-	-	-	ns
	V _{CC} = 2.0 V		-	39	75	-	90	ns	
		$V_{CC} = 2.7 \text{ V}$		-	29	55	-	66	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[2]	-	22	44	-	53	ns
		$V_{CC} = 3.3 \text{ V}; C_L = 15 \text{ pF}$		-	18	-	-	-	ns
		STR to QPn; see Figure 9	<u>[3]</u>						
		V _{CC} = 1.2 V		-	105	-	-	-	ns
		V _{CC} = 2.0 V		-	36	68	-	82	ns
		$V_{CC} = 2.7 \text{ V}$		-	26	50	-	60	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[2]	-	20	40	-	48	ns
		$V_{CC} = 3.3 \text{ V}; C_L = 15 \text{ pF}$		-	17	-	-	-	ns
en	enable time	OE to QPn; see Figure 11	[4]						
		V _{CC} = 1.2 V		-	100	-	-	-	ns
		V _{CC} = 2.0 V		-	34	65	-	77	ns
		$V_{CC} = 2.7 \text{ V}$		-	25	48	-	56	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[2]	-	19	38	-	45	ns
dis	disable time	OE to QPn; see Figure 11	<u>[5]</u>						
		V _{CC} = 1.2 V		-	65	-	-	-	ns
		V _{CC} = 2.0 V		-	24	40	-	49	ns
		V _{CC} = 2.7 V		-	18	32	-	37	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[2]	-	14	26	-	30	ns

8-stage shift-and-store bus register

 Table 7.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; for test circuit see Figure 12.

Symbol	Parameter	Conditions		-40	°C to 85	°C	–40 °C	to +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
t _W	pulse width	CP HIGH or LOW; see Figure 8							
		V _{CC} = 2.0 V		34	9	-	41	-	ns
		V _{CC} = 2.7 V		25	6	-	30	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[2]	20	5	-	24	-	ns
		STR HIGH; see Figure 9							
		V _{CC} = 2.0 V		34	9	-	41	-	ns
		V _{CC} = 2.7 V		25	6	-	30	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[2]	20	5	-	24	-	ns
t _{su}	set-up time	D to CP; see Figure 10							
		V _{CC} = 1.2 V		-	25	-	-	-	ns
		V _{CC} = 2.0 V		22	9	-	26	-	ns
		V _{CC} = 2.7 V		16	6	-	19	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[2]	13	5	-	15	-	ns
		CP to STR; see Figure 9							
		V _{CC} = 1.2 V		-	50	-	-	-	ns
		V _{CC} = 2.0 V		43	17	-	51	-	ns
		V _{CC} = 2.7 V		31	13	-	38	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[2]	25	10	-	30	-	ns
t _h	hold time	D to CP; see Figure 10							
		V _{CC} = 1.2 V		-	-10	-	-	-	ns
		V _{CC} = 2.0 V		5	-4	-	+5	-	ns
		V _{CC} = 2.7 V		5	-3	-	+5	-	ns
		V _{CC} = 3.0 V to 3.6 V	[2]	5	-2	-	+5	-	ns
		CP to STR; see Figure 9							
		V _{CC} = 1.2 V		-	-25	-	-	-	ns
		V _{CC} = 2.0 V		5	-9	-	+5	-	ns
		$V_{CC} = 2.7 \text{ V}$		5	-6	-	+5	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[2]	5	-5	-	+5	-	ns
f _{max}	maximum	CP; see Figure 8							
	frequency	V _{CC} = 2.0 V		14	52	-	12	-	MHz
		$V_{CC} = 2.7 \text{ V}$		19	70	-	16	-	MHz
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		24	87	-	20	-	MHz
		$V_{CC} = 3.3 \text{ V}; C_L = 15 \text{ pF}$	[2]	-	95	-	-	-	MHz

8-stage shift-and-store bus register

Table 7. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; for test circuit see Figure 12.

Symbol	Parameter	Conditions	-40	°C to 85	°C	–40 °C t	Unit	
			Min	Typ[1]	Max	Min	Max	
C_{PD}	power dissipation capacitance	$C_L = 50 \text{ pF}; f = 1 \text{ MHz};$ $V_I = \text{GND to } V_{CC}$	-	83	-	-	-	pF

- [1] All typical values are measured at T_{amb} = 25 °C.
- [2] All typical values are measured at $V_{CC} = 3.3 \text{ V}$.
- [3] t_{pd} is the same as t_{PLH} and t_{PHL} .
- [4] t_{en} is the same as t_{PZH} and t_{PZL} .
- [5] t_{dis} is the same as t_{PLZ} and t_{PHZ} .
- [6] t_t is the same as t_{THL} and t_{TLH} .
- [7] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$$
 where:

f_i = input frequency in MHz;

fo = output frequency in MHz;

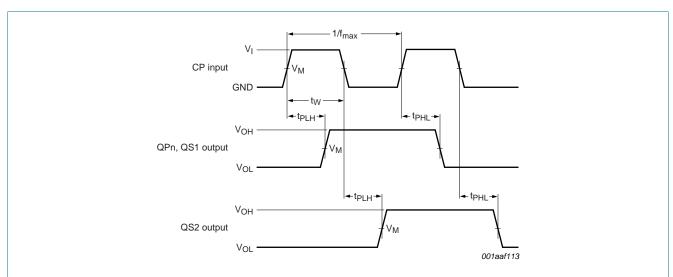
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$

12. Waveforms



Measurement points are given in Table 8.

 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 8. Propagation delay input (CP) to output (QPn, QS1, QS2), output transition time, clock input (CP) pulse width and the maximum frequency (CP)

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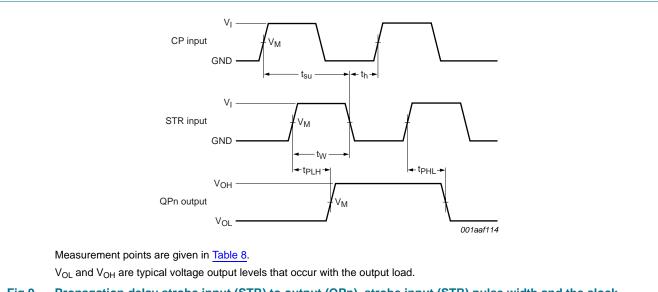
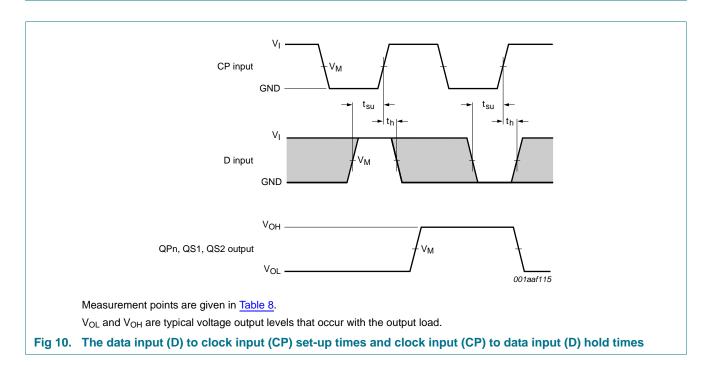
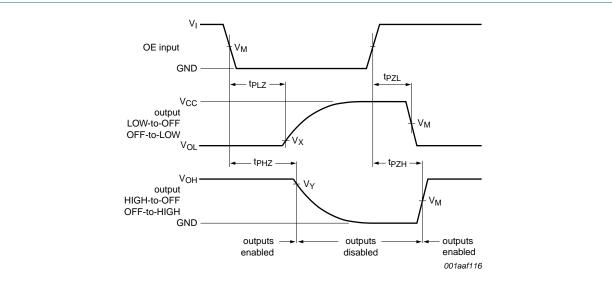


Fig 9. Propagation delay strobe input (STR) to output (QPn), strobe input (STR) pulse width and the clock set-up and hold times for strobe input



8-stage shift-and-store bus register



Measurement points are given in Table 8.

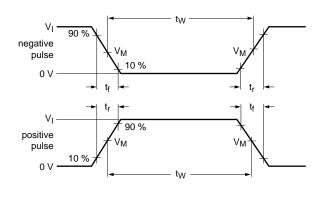
 $\rm V_{OL}$ and $\rm V_{OH}$ are typical voltage output levels that occur with the output load.

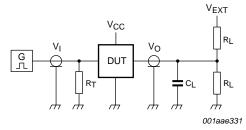
Fig 11. Enable and disable times

Table 8. Measurement points

Supply voltage	Input	Output	Output					
V _{CC}	V _M	V_{M}	V _X	V _Y				
< 2.7 V	0.5V _{CC}	0.5V _{CC}	$V_{OL} + 0.1V_{CC}$	$V_{OH}-0.1V_{CC} \\$				
2.7 V to 3.6 V	1.5 V	1.5 V	V _{OL} + 0.3 V	V _{OH} – 0.3 V				

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Test data is given in Table 9.

Definitions for test circuit:

 R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Fig 12. Test circuit for measuring switching times

Table 9. Test data

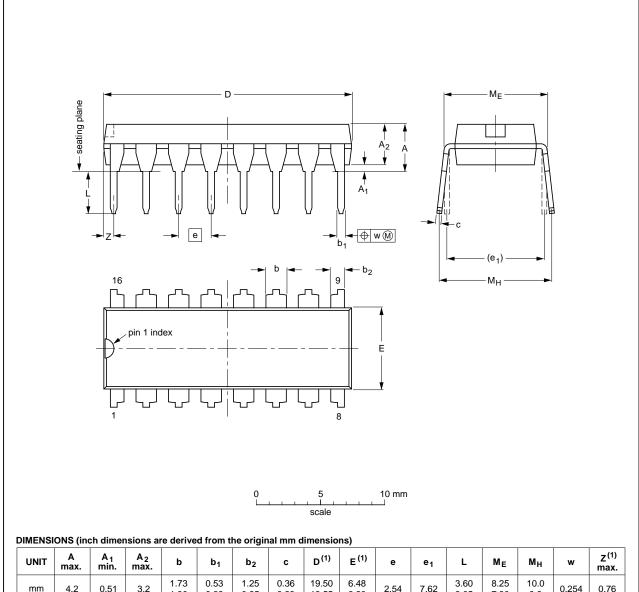
Supply voltage	Input		Load		V _{EXT}				
V _{CC}	VI	t _r , t _f	CL	R _L	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}		
< 2.7 V	V_{CC}	\leq 2.5 ns	50 pF	1 kΩ	open	GND	2V _{CC}		
2.7 V to 3.6 V	2.7 V	≤ 2.5 ns	15 pF, 50 pF	1 kΩ	open	GND	2V _{CC}		

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13. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	b ₂	C	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.03

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

	OUTLINE		REFERENCES						
VERSION		IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE		
	SOT38-4						95-01-14 03-02-13		
							03-02-		

Fig 13. Package outline SOT38-4 (DIP16)

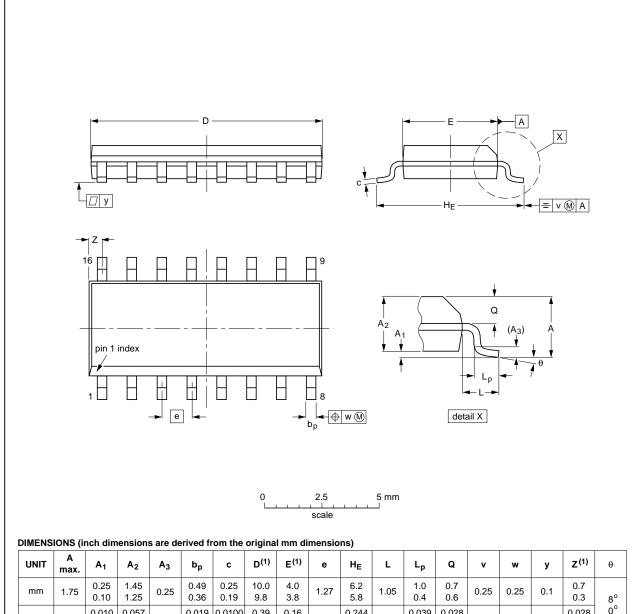
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8-stage shift-and-store bus register

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	σ	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		KEFEK	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012				99-12-27 03-02-19

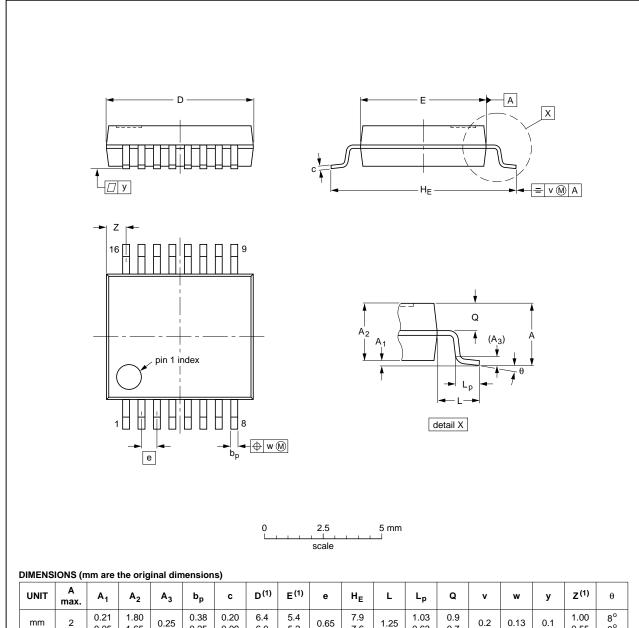
Fig 14. Package outline SOT109-1 (SO16)

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SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



UNIT	A max.	A ₁	A ₂	A ₃	b _p	С	D ⁽¹⁾	E ⁽¹⁾	e	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

Note

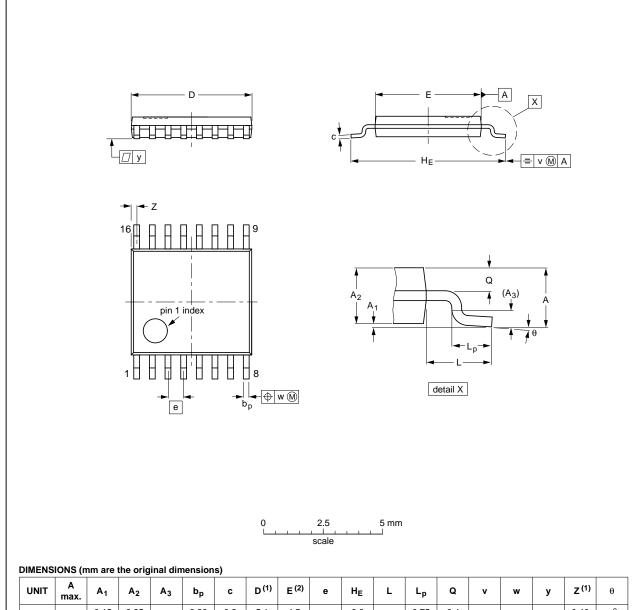
1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	REFERENCES EUROPEAN ISSUI					
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE		
SOT338-1		MO-150				99-12-27 03-02-19		
	VERSION	VERSION IEC	VERSION IEC JEDEC	VERSION IEC JEDEC JEITA	VERSION IEC JEDEC JEITA	VERSION IEC JEDEC JEITA PROJECTION		

Fig 15. Package outline SOT338-1 (SSOP16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



-							-,												
	UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
	mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT403-1		MO-153			99-12-27 03-02-18

Fig 16. Package outline SOT403-1 (TSSOP16)

8-stage shift-and-store bus register

14. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

15. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LV4094 v.4	20111219	Product data sheet	-	74LV4094 v.3
Modifications:	 Legal page 	s updated.		
74LV4094 v.3	20110307	Product data sheet	-	74LV4094 v.2
74LV4094 v.2	20060629	Product data sheet	-	74LV4094 v.1
74LV4094 v.1	19980623	Product specification	-	-

8-stage shift-and-store bus register

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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74LV4094

8-stage shift-and-store bus register

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8-stage shift-and-store bus register

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